

Abstract Submitted
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First-principles simulations of exciton diffusion in organic semiconductors XU ZHANG, ZI LI, GANG LU, Department of Physics and Astronomy, California State University Northridge — Exciton diffusion is of great importance to the performance of organic optoelectronic devices, including organic photovoltaics and solid-state lighting. The ability to control exciton diffusion in organic semiconductors is crucial to the design of efficient optoelectronic devices. However, such ability can only be achieved through a fundamental understanding of exciton diffusion mechanism. We have proposed a first-principles based frame work that can predict exciton dynamics in organic semiconductors. The framework is based on time-dependent density functional theory to provide the energy and many-body wave functions of excitons. Nonadiabatic *ab initio* molecular dynamics is used to calculate phonon-assisted transition rates between localized exciton states. Using Monte Carlo simulations, we determine exciton diffusion length, lifetime, diffusivity, and harvesting efficiency in poly(3-hexylthiophene) polymers at different temperatures, and the results agree very well with corresponding experimental values. We find that exciton diffusion is primarily determined by the density of states of low-energy excitons; a widely speculated diffusion mechanism has been confirmed and elucidated by the simulations. Some general guidelines for designing more efficient organic solar cells can be gleaned from the simulation results

Xu Zhang
Department of Physics and Astronomy,
California State University Northridge

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